## Driver Transistors

## FEATURES

- We declare that the material of product compliance with RoHS requirements.
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

LMBTA05LT1G
LMBTA06LT1G S-LMBTA05LT1G S-LMBTA06LT1G

## MAXIMUM RATINGS

| Rating | Symbol | Value <br> LIMBTA05 LMBTA06 |  |  |  | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| Collector-Emitter Voltage | $\mathrm{V}_{\text {ceo }}$ | 60 | 80 | Vdc |  |  |
| Collector-Base Voltage | $\mathrm{V}_{\text {cbo }}$ | 60 | 80 | Vdc |  |  |
| Emitter-Base Voltage | $\mathrm{V}_{\text {Ebo }}$ | 4.0 | Vdc |  |  |  |
| Collector Current - Continuous | $\mathrm{I}_{\mathrm{c}}$ | 500 | mAdc |  |  |  |

## THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
| :--- | :---: | :---: | :---: |
| Total Device Dissipation FR-5 Board, (1) | $\mathrm{P}_{\mathrm{D}}$ | 225 | mW |
| $\mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 1.8 | $\mathrm{~mW} /{ }^{\circ} \mathrm{C}$ |
| Derate above $25^{\circ} \mathrm{C}$ |  | 556 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Thermal Resistance, Junction to Ambient | $\mathrm{R}_{\text {өJA }}$ | mW |  |
| Total Device Dissipation | $\mathrm{P}_{\mathrm{D}}$ | 300 | mW |
| Alumina Substrate, (2) $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 2.4 | $\mathrm{~mW} /{ }^{\circ} \mathrm{C}$ |
| Derate above $25^{\circ} \mathrm{C}$ |  | $\mathrm{R}_{\text {өJA }}$ | 417 |
| Thermal Resistance, Junction to Ambient | $\mathrm{T}_{J}, \mathrm{~T}_{\text {stg }}$ | -55 to +150 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Junction and Storage Temperature |  |  |  |



## DEVICE MARKING

## (S-)LMBTA05LT1G $=1 \mathrm{H},(\mathrm{S}-$ )LMBTA06LT1G $=1 \mathrm{GM} ;$

ELECTRICAL CHARACTERISTICS ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted.)

| Characteristic | Symbol | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |

OFF CHARACTERISTICS

| Collector-Emitter Breakdown Voltage(3) |  | $\mathrm{V}_{\text {(BR) }}$ ceo |  |  | Vdc |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\left(\mathrm{I}_{\mathrm{C}}=1.0 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=0\right)$ | LMBTA05 |  | 60 | - |  |
|  | LMBTA06 |  | 80 | - |  |
| Emitter-Base Breakdown Voltage $\left(I_{E}=100 \mu \mathrm{Adc}, \mathrm{I}_{\mathrm{C}}=0\right)$ |  | $\mathrm{V}_{\text {(BR) }{ }^{\text {ebo }}}$ | 4.0 | - | Vdc |
| Collector Cutoff Current $\left(\mathrm{V} \mathrm{CE}=60 \mathrm{Vdc}, \mathrm{I}_{\mathrm{B}}=0\right.$ ) |  | $I_{\text {ces }}$ | - | 0.1 | $\mu \mathrm{Adc}$ |
| Emitter Cutoff Current $\begin{aligned} & \left(V_{C B}=60 V d c, I_{E}=0\right) \\ & \left(V_{C B}=80 V d c, I_{E}=0\right) \end{aligned}$ | LMBTA05 <br> LMBTA06 | $I_{\text {cbo }}$ | - | 0.1 0.1 | $\mu \mathrm{Adc}$ |

1. $\mathrm{FR}-5=1.0 \times 0.75 \times 0.062 \mathrm{in}$.
2. Alumina $=0.4 \times 0.3 \times 0.024 \mathrm{in} .99 .5 \%$ alumina.
3. Pulse Test: Pulse Width $\leq 300 \mu \mathrm{~s}$, Duty Cycle $\leq 2.0 \%$.

## LMBTA05LT1G LMBTA06LT1G S-LMBTA05LT1G S-LMBTA06LT1G

ELECTRICAL CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$ unless otherwise noted) (Continued)


SMALL-SIGNAL CHARACTERISTICS

| Current -Gain - Bandwidth Product(4) <br> $\left(V_{C E}=2.0 ~ V, I_{C}=10 \mathrm{~mA}, \mathrm{f}=100 \mathrm{MHz}\right)$ | $\mathrm{f}_{\mathrm{T}}$ | 100 |
| :--- | :--- | :--- | MHz

4. $f_{T}$ is defined as the frequency at which $\left|h f_{e}\right|$ extrapolates to unity.

## ORDERING INFORMATION

| Device | Marking | Shipping |
| :---: | :---: | :---: |
| (S-)LMBTA05LT1G | 1H | $3000 /$ Tape \& Reel |
| (S-)LMBTA06LT1G | 1GM | $3000 /$ Tape \& Reel |
| (S-)LMBTA05LT3G | 1H | 10000/Tape \& Reel |
| (S-)LMBTA06LT3G | 1GM | $10000 /$ Tape \& Reel |

LESHAN RADIO COMPANY, LTD.
LMBTA05LT1G LMBTA06LT1G S-LMBTA05LT1G S-LMBTA06LT1G

## SOT-23



## NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

| DIM | INCHES |  | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |
| A | 0.1102 | 0.1197 | 2.80 | 3.04 |
| B | 0.0472 | 0.0551 | 1.20 | 1.40 |
| C | 0.0350 | 0.0440 | 0.89 | 1.11 |
| D | 0.0150 | 0.0200 | 0.37 | 0.50 |
| G | 0.0701 | 0.0807 | 1.78 | 2.04 |
| H | 0.0005 | 0.0040 | 0.013 | 0.100 |
| J | 0.0034 | 0.0070 | 0.085 | 0.177 |
| K | 0.0140 | 0.0285 | 0.35 | 0.69 |
| L | 0.0350 | 0.0401 | 0.89 | 1.02 |
| S | 0.0830 | 0.1039 | 2.10 | 2.64 |
| V | 0.0177 | 0.0236 | 0.45 | 0.60 |

PIN 1. BASE
2. EMITTER
3. COLLECTOR


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